



2812

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)

Shunpei YAMAZAKI et al.)

Serial No. 09/362,192)

Filed: July 28, 1999) Group Art Unit: 2812

For: SEMICONDUCTOR DEVICE) Examiner: V. Simkovic
HAVING SEMICONDUCTOR)
CIRCUIT COMPRISING)
SEMICONDUCTOR ELEMENT)
AND METHOD FOR)
MANUFACTURING THE SAME)

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AMENDMENT AND RESPONSE TO ELECTION REQUIREMENT

Honorable Commissioner for Patents

Washington, D.C. 20231

Sir:

In response to the Office Action of March 16, 2001, please amend the subject application as follows:

IN THE CLAIMS:

Cancel claims 29-44 without prejudice to applicants' right to file a division application with respect thereto.

Please amend claim 52 as follows:

52. (Amended) A method for manufacturing a semiconductor device comprising steps of:

contacting a material for promoting crystallization to at least a part of an initial semiconductor film formed over a substrate;

subjecting said semiconductor film to oxygen plasma; and

crystallizing said initial semiconductor film using said material, to obtain a crystalline semiconductor film.

Please add new claims 60-66 as follows:

